

Product Catalog

Advanced Switching and Magnetic Sensing Solutions

REDROCK™ RR110 TMR ANALOG SENSOR





RedRock™ RR110 TMR Analog Sensor

The RedRock 110 Series is an analog magnetic sensor, ideal for use in medical, industrial, automotive, and consumer applications. Based on patented Tunneling Magnetoresistance (TMR) technology, the RR110 Series excels even in low magnetic fields and with large air gaps. The RR110 Series offers high sensitivity in a small footprint package.

Features

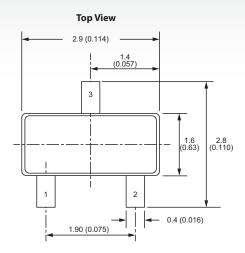
- ▶ High sensitivity
- ▶ Stable temperature performance
- ▶ Resistant to mechanical stress
- ▶ REACH Compliant
- ▶ RoHS Compliant (Pb)

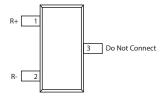


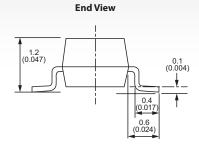
IDEAL APPLICATIONS

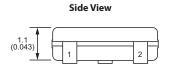
- ▶ Door or lid closure detection
- ► Smart phones, tablets and laptops
- ▶ Proximity detection
- ▶ Position sensing
- ▶ Water, electric and gas meters
- ▶ Fluid level detection

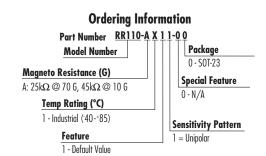
DIMENSIONS











REDROCK™ RR110 TMR ANALOG SENSOR

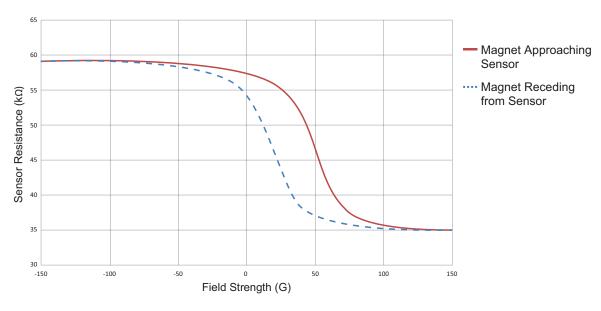
REDROCK™	RR110					
Parameters ¹	Units	Min	Тур	Max		
OPERATING CHARACTERISTICS ²						
Resistance @70 Gauss	kΩ		25			
Resistance @10 Gauss	kΩ		45			
Operate Time	nS		600			
Release Time	nS		600			
ELECTRICAL CHARACTERISTICS						
Supply Voltage	V_{cc}			15		
Operating Current	mA			1		
ABSOLUTE ENVIRONMENTAL RATINGS						
Operating Temperature: Industrial	۰C	-40		85		
Storage Temperature	°C	-55		150		
Soldering Temperature (3 cycles of 1 min.)	°C			260		
Operating Magnetic Field	G			100		
ESD Level (HBM) ³	V			N/A		

Notes:

- 1. Contact factory for more information on additional product offerings.
- 2. All characteristics as measured at 25°C
- 3. ESD PRECAUTIONS MUST BE USED WHEN HANDLING.

MAGNETIC SENSITIVITY TRANSFER CURVE

The magnetic sensitivity transfer curve illustrates the characteristic behavior of an analog TMR sensor's resistance change as the strength of an applied magnetic field changes. The magnet approach curve (red line) shows the change in resistance as the strength of an applied magnetic field increases. The magnet recede curve (blue dashed line) shows the change in resistance as the strength of an applied magnetic field decreases. Alternatively, you can think of the resistance going down the blue slope as a magnet approaches the sensor, and going up the red slope as the magnet moves further away from the sensor.





REDROCK™ RR120 TMR DIGITAL SENSOR





RedRock™ RR120 TMR Digital Sensor

The RedRock 120 Series is an integrated digital magnetic sensor ideal for use in medical, industrial, automotive and consumer switching applications. Based on patented Tunneling Magnetoresistance (TMR) technology with CMOS process, the RR120 Series can function even in low magnetic fields with large air gaps. The RR120 Series provides high sensitivity with low power consumption in a small footprint package.

Features

- ▶ High sensitivity
- ▶ Stable temperature performance
- ▶ Resistant to mechanical stress
- ▶ Low power consumption
- ▶ High frequency performance
- ▶ Logic output for design flexibility
- ▶ REACH Compliant
- ▶ RoHS Compliant (Pb)

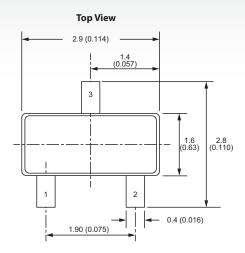


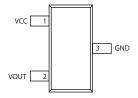
IDEAL APPLICATIONS

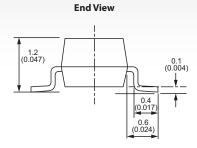
- ▶ Door or lid closure detection
- ▶ Smart phones, tablets and laptops
- ▶ Bare glass reed switch replacement
- ▶ Motor controllers
- ▶ Proximity detection
- ▶ Open-close detection
- ▶ Water, electric and gas meters
- ▶ Fluid level detection
- "Wake-Up" functionality

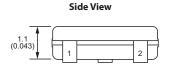
DIMENSIONS

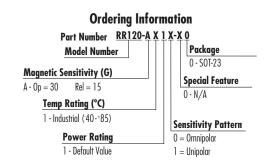
in Millimeters (Inches)











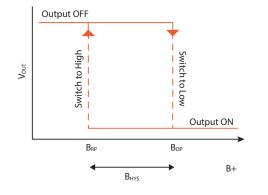
REDROCK™ RR120 TMR DIGITAL SENSOR

REDROCK™	RR120					
Parameters	Units	Min	Тур	Max		
OPERATING CHARACTERISTICS ¹						
Operate Sensitivity	G	20	30	40		
Release Sensitivity	G	8	15	25		
Hysteresis	%		50			
Operate Time	nS		600			
Release Time	nS		600			
ELECTRICAL CHARACTERISTICS ¹						
Supply Voltage	V_{cc}	2.7	3.0	3.3		
Average Current Drain	nA		350	400		
Output Voltage (High) ²	V_{outh}		2.7 V			
Output Voltage (Low) ²	V_{outl}		0.2 V			
ABSOLUTE ENVIRONMENTAL RATINGS						
Operating Temperature: Industrial	°C	-40		85		
Storage Temperature	۰C	-55		150		
Soldering Temperature (3 cycles, 1 min.)	۰C			260		
Operating Magnetic Field	G			100		
ESD Level (HBM)	V			4000		

Notes:

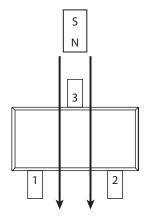
- 1. All characteristics as measured at 25°C
- 2. See "Output Behavior vs. Magnetic Field" below for more details.

OUTPUT BEHAVIOR VS. MAGNETIC FIELD

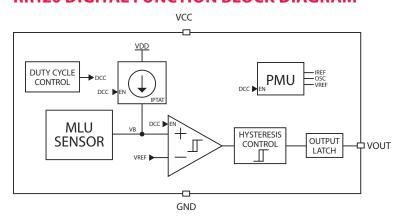


Characteristic	Conditions	Output
North Pole	B > B _{OP}	Low
Null or Weak Magnetic Field	B < B _{RP}	High
South Pole	B > B _{OP}	High

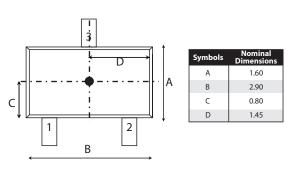
SENSOR POLARITY DIAGRAM



RR120 DIGITAL FUNCTION BLOCK DIAGRAM



MLU SENSOR LOCATION DIAGRAM



rev. 09152016

REDROCK™ RR130 TMR DIGITAL SWITCH





RedRock™ RR130 TMR Digital Switch

The RedRock 130 Series is an integrated digital magnetic switch ideal for use in medical, industrial, automotive and consumer switching applications. It is based on patented Tunneling Magnetoresistance (TMR) technology with integrated CMOS process. The RR130 Series can operate in low magnetic fields with large air gaps. The open drain output can interface with a system voltage up to 6V for added design flexibility. The RR130 Series provides high sensitivity with low power consumption in a small footprint package.

Features

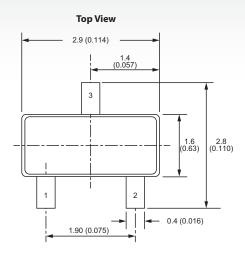
- ▶ High sensitivity
- ▶ Stable temperature performance
- ▶ Resistant to mechanical stress
- ▶ Low power consumption
- ▶ High frequency performance
- Open drain MOSFET for design flexibility
- ▶ REACH Compliant
- ▶ RoHS Compliant (Pb)

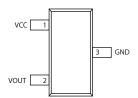
IDEAL APPLICATIONS

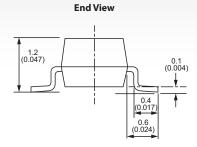
- ▶ Door or lid closure detection
- ► Smart phones, tablets and laptops
- ▶ Bare glass reed switch replacement
- ▶ Motor controllers
- ▶ Proximity detection
- ▶ Power switch or open-close detection
- ▶ Water, electric and gas meters
- ▶ Fluid level detection
- "Wake-Up" functionality

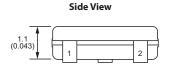
DIMENSIONS

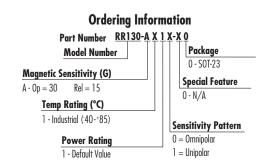
in Millimeters (Inches)











REDROCK™ RR130 TMR DIGITAL SWITCH

REDROCK™			RR130		
Parameters	Units	Min	Тур	Max	
OPERATING CHARACTERISTICS ¹					
Operate Sensitivity	G	20	30	40	
Release Sensitivity	G	8	15	25	
Hysteresis	%		50		
Operate Time	nS		600		
Release Time	nS		600		
ELECTRICAL CHARACTERISTICS ¹					
Supply Voltage ² (V _{cc})	V	2.7	3.0	3.3	
Average Current Drain	nA		350	400	
System Voltage ² (V _{sys})	V			6	
System Current ² (I _{sys})	mA			15	
ABSOLUTE ENVIRONMENTAL RATINGS					
Operating Temperature: Industrial	۰C	-40		85	
Storage Temperature	°C	-55		150	
Soldering Temperature	۰C			260	
Max. Exposed Magnetic Field	G			100	
ESD Level (HBM)	V			4000	

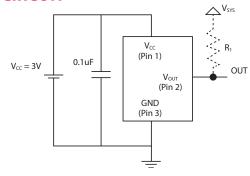
Notes:

- 1. All characteristics as measured at 25°C
- 2. See "Application Circuit" for more information.

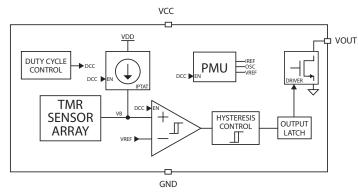
APPLICATION CIRCUIT

RR130 Open Drain Output Application Circuit

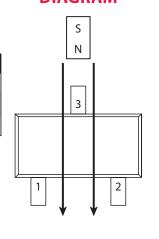
With the open drain output, the system voltage can range up to 6V. Please keep in mind the supply to the RR130 must remain at 3V. A decoupling capacitor between the supply voltage and ground is recommended with placement close to the magnetic sensor. A typical capacitor value of 0.1 uF will suffice.



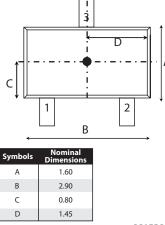
RR130 DIGITAL FUNCTION BLOCK DIAGRAM



SENSOR POLARITY DIAGRAM

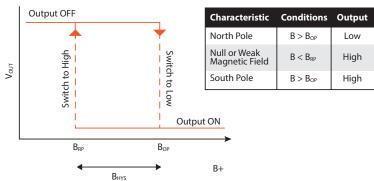


MLU SENSOR LOCATION DIAGRAM



rev. 09152016

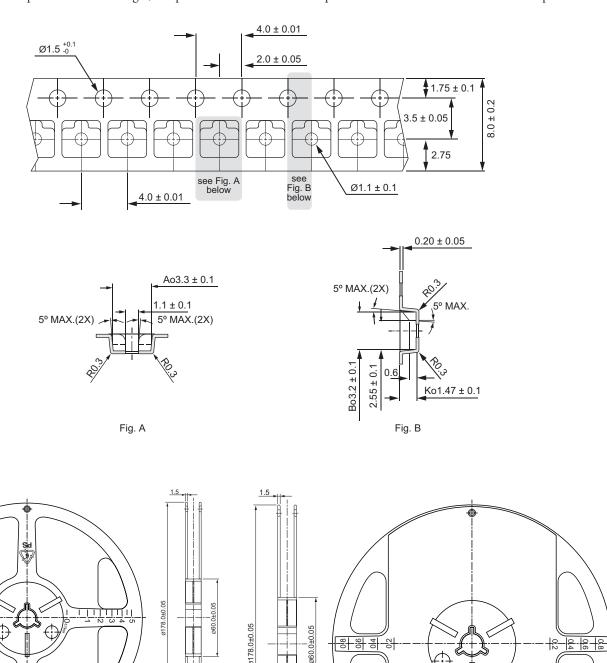
OUTPUT BEHAVIOR VS. MAGNETIC FIELD



TMR TECHNICAL & APPLICATIONS INFORMATION

TMR SENSOR & SWITCH PACKAGING

Standard packaging is Tape & Reel containing 3,000 pieces. Below is a chart of Tape & Reel dimensions for standard TMR products.



0 0 0 8

EľAJ

8 8 8 8

9.0 +1.5

<u>ν α</u>

2.2±0.05

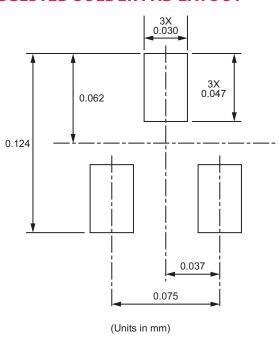
10.6

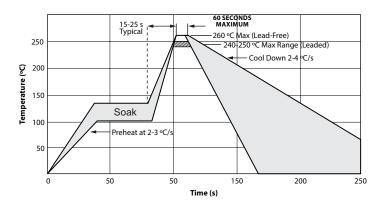
ø13.5±0.05

9.0 +1.5

SUGGESTED SOLDER PAD LAYOUT

SUGGESTED REFLOW PROFILE





Notes:

- 1. Fully compatible with standard no-lead solder profile, 260 °C for 1 minute max (3 cycles max)
- 2. Profile shown as example. Users are advised to develop their own board-level profile
- 3. Temperature tolerance: +0 °C, as measured at any point on the package or leads
- 4. MSL listed on main specification page compatible with J-STD-020 or equiv.

TMR TECHNICAL & APPLICATIONS INFORMATION

GLOSSARY OF TERMS

Hysteresis: Hysteresis refers to the difference between two points of interest for a particular device. For digital sensors and switches, it represents the difference between the operate sensitivity and the release sensitivity, expressed either as an absolute value (Bop – Brp) or the % difference (Bop – Brp)/Bop. For an analog sensor, the hysteresis is the difference between the "magnet approach curve" and the "magnet recede curve."

Magnet Approach Curve: The magnet approach curve is the characteristic change in resistance of an analog TMR sensor as an applied magnetic field approaches the sensor, typically plotted as a function of the magnetic field strength.

Magnet Recede Curve: The magnet recede curve is the characteristic change in resistance of an analog TMR sensor as an applied magnetic field recedes from the sensor, typically plotted as a function of the magnetic field strength.

Magnetoresistance: Magnetoresistance is a phenomenon wherein the electrical resistance of certain materials changes when exposed to an externally-applied magnetic field.

Magnetic Transfer Curve: The magnetic transfer curve defines the characteristic behavior of an analog TMR sensor by combining both the magnet approach curve and the magnet receive curve together.

Magnetic Tunnel Junction: A magnetic tunnel junction is a thin film structure consisting of two magnetic layers separated by a thin insulator. Because the insulating layer is thin enough (typically a few nanometers), electrons can tunnel from one magnetic layer into the other.

Operate Sensitivity: The operate sensitivity defines the upper limit of the strength of an applied magnetic field that a digital TMR sensor or switch must operate.

Operate Time: The operate time is the difference, in time, between the application of a magnetic field and the output response of the device. In an analog sensor, the response is a change in output resistance. In a digital sensor, the response is a change in state of the electrical output.

Release Sensitivity: The release sensitivity defines the lower limit of the strength of an applied magnetic field that a digital TMR sensor or switch must release.

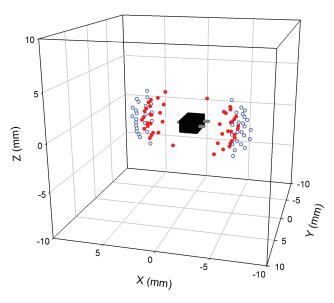
Release Time: The release time is the difference, in time, between the removal of an applied magnetic field and the output response of the device. In an analog sensor, the response is a change in output resistance. In a digital sensor, the response is a change in state of the electrical output.

Tunnel Magnetoresistance (TMR): Tunnel Magnetoresistance is the magnetoresistive effect that occurs in a magnetic tunnel junction.

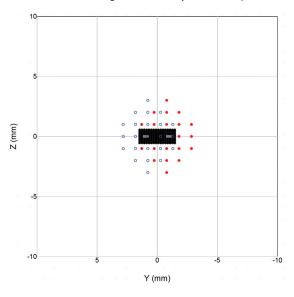
MAGNETIC SENSITIVITY MAPS

Magnetic sensitivity maps show the operate and release loci in threedimensional space when a magnet is presented to a magnetically operated switch or sensor. The absolute operate and release distances between the magnet and the sensor will vary depending on the sensitivity of the switch and the strength of the magnet. However, the shape and direction of the operate loci stay relatively constant except for cases where the magnet is physically much larger than the sensor. These plots were generated using a 2mm³ cubic shaped NdFeB N52 magnet with its North pole presented to the ground pin and a South pole presented to the opposite side. The X, Y, and Z axes have their origin (0,0,0) at the geometric center of the TMR device.

RR120/RR130 Magnetic Sensitivity Pattern, perspective view

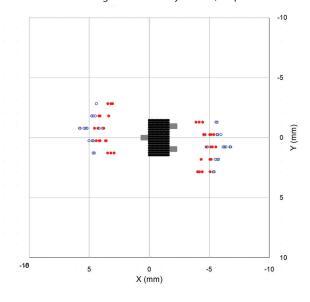


RR120/RR130 Magnetic Sensitivity Pattern, YZ plane

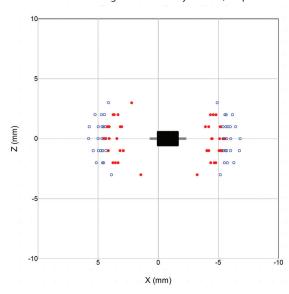


Operate PointsRelease Points

RR120/RR130 Magnetic Sensitivity Pattern, XY plane



RR120/RR130 Magnetic Sensitivity Pattern, XZ plane



rev. 09152016



66 Whitecap Drive North Kingstown, RI 02852

401-943-2686 • Fax: 401-942-0920

 $www.cotorelay.com \bullet redrock@cotorelay.com$